

FEATURES

Bandwidth: >400 MHz

Low insertion loss and on resistance: 2.2 Ω typical

On resistance flatness: 0.3 Ω typical

Single 3 V/5 V supply operation

Very low distortion: <0.3%

Low quiescent supply current: 1 nA typical

Fast switching times

$t_{ON} = 6 \text{ ns}$

$t_{OFF} = 3 \text{ ns}$

TTL-/CMOS-compatible

Pb-free packages

16-lead QSSOP

16-lead 3 mm $\times$ 3 mm body LFCSP

FUNCTIONAL BLOCK DIAGRAM

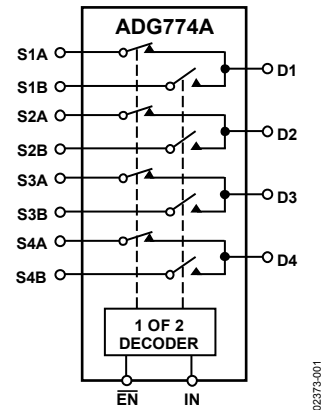


Figure 1.

GENERAL DESCRIPTION

The ADG774A is a monolithic CMOS device comprising four 2:1 multiplexer/demultiplexers with high impedance outputs. The CMOS process provides low power dissipation yet offers high switching speed and low on resistance. The on resistance variation is typically less than 0.5 Ω over the input signal range.

The bandwidth of the ADG774A is typically 400 MHz and this, coupled with low distortion (typically 0.3%), makes the part suitable for switching of high speed data signals.

The on resistance profile is very flat over the full analog input range ensuring excellent linearity and low distortion. CMOS construction ensures ultralow power dissipation.

The ADG774A operates from a single 3.3 V/5 V supply and is TTL logic-compatible. The control logic for each switch is shown in the truth table (see Table 5).

These switches conduct equally well in both directions when on. In the off condition, signal levels up to the supplies are blocked. The ADG774A switches exhibit break-before-make switching action.

PRODUCT HIGHLIGHTS

1. Wide bandwidth data rates of >400 MHz.
2. Ultralow power dissipation.
3. Low leakage over temperature.
4. Break-before-make switching prevents channel shorting when the switches are configured as a multiplexer.
5. Crosstalk is typically -70 dB @ 10 MHz.
6. Off isolation is typically -65 dB @ 10 MHz.
7. Available in compact 3 mm $\times$ 3 mm LFCSP.

Rev. B

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

TABLE OF CONTENTS

Features	1	ESD Caution.....	5
Functional Block Diagram	1	Pin Configurations and Function Descriptions	6
General Description	1	Typical Performance Characteristics	7
Product Highlights	1	Test Circuits.....	9
Revision History	2	Terminology	11
Specifications.....	3	Application Circuits	12
Single Supply	3	Outline Dimensions	13
Absolute Maximum Ratings.....	5	Ordering Guide	13

REVISION HISTORY

8/06—Rev. A to Rev. B		4/03—Rev. 0 to Rev. A	
Updated Format.....	Universal	Changes to TPCs 9–11	5
Added LFCSP Model.....	Universal	Updated Outline Dimensions	8
Added Lead-Free Models	Universal		
Changes to Table 3.....	5	7/01—Revision 0: Initial Version	
Updated Outline Dimensions	13		
Changes to Ordering Guide	13		

SPECIFICATIONS

SINGLE SUPPLY

$V_{DD} = 5\text{ V} \pm 10\%$, $GND = 0\text{ V}$, all specifications T_{MIN} to T_{MAX} , unless otherwise noted.¹

Table 1.

Parameter	B Version		Unit	Test Conditions/Comments
	25°C	T _{MIN} to T _{MAX}		
ANALOG SWITCH				
Analog Signal Range		0 to 2.5	V	
On Resistance, R _{ON}	2.2		Ω typ	V _D = 0 V to 1 V, I _S = −10 mA
	3.5	4	Ω max	
On Resistance Match Between Channels, ΔR _{ON}	0.15		Ω typ	V _D = 0 V to 1 V, I _S = −10 mA
		0.5	Ω max	
On Resistance Flatness, R _{FLAT(ON)}	0.3		Ω typ	V _D = 0 V to 1 V, I _S = −10 mA
		0.6	Ω max	
LEAKAGE CURRENTS				
Source Off Leakage, I _S (OFF)	±0.001		nA typ	V _D = 3 V/1 V, V _S = 1 V/3 V, see Figure 17
	±0.1	±0.25	nA max	
Drain Off Leakage, I _D (OFF)	±0.001		nA typ	V _D = 3 V/1 V, V _S = 1 V/3 V, see Figure 17
	±0.1	±0.25	nA max	
Channel On Leakage, I _D , I _S (ON)	±0.001		nA typ	V _D = V _S = 3 V/1 V, see Figure 18
	±0.1	±0.25	nA max	
DIGITAL INPUTS				
Input High Voltage, V _{INH}		2.4	V min	
Input Low Voltage, V _{INL}		0.8	V max	
Input Current				
I _{INL} or I _{INH}	0.001		μA typ	V _{IN} = V _{INL} or V _{INH}
		±0.1	μA max	
Digital Input Capacitance, C _{IN}		3	pF typ	
DYNAMIC CHARACTERISTICS ²				
t _{ON} , t _{ON} ($\overline{\text{EN}}$)		6	ns typ	C _L = 35 pF, R _L = 50 Ω, V _S = 2 V, see Figure 22
		12	ns max	
t _{OFF} , t _{OFF} ($\overline{\text{EN}}$)		3	ns typ	C _L = 35 pF, R _L = 50 Ω, V _S = 2 V, see Figure 22
		6	ns max	
Break-Before-Make Time Delay, t _D		3	ns typ	C _L = 35 pF, R _L = 50 Ω, V _{S1} = V _{S2} = 2 V, see Figure 23
		1	ns min	
Off Isolation		−65	dB typ	f = 10 MHz, R _L = 50 Ω, see Figure 20
Channel-to-Channel Crosstalk		−70	dB typ	f = 10 MHz, R _L = 50 Ω, see Figure 21
Bandwidth −3 dB		400	MHz typ	R _L = 50 Ω, see Figure 19
Distortion		0.3	% typ	R _L = 100 Ω
Charge Injection		6	pC typ	C _L = 1 nF, see Figure 24, V _S = 0 V
C _S (OFF)		5	pF typ	
C _D (OFF)		7.5	pF typ	
C _D , C _S (ON)		12	pF typ	
POWER REQUIREMENTS				
I _{DD}		1	μA max	V _{DD} = 5.5 V
	0.001		μA typ	Digital inputs = 0 V or V _{DD}

¹ Temperature range for B version is -40°C to $+85^\circ\text{C}$.

² Guaranteed by design, not subject to production test.

ADG774A

$V_{DD} = 3\text{ V} \pm 10\%$, $GND = 0\text{ V}$, all specifications T_{MIN} to T_{MAX} , unless otherwise noted.¹

Table 2.

Parameter	B Version		Unit	Test Conditions/Comments
	25°C	T _{MIN} to T _{MAX}		
ANALOG SWITCH				
Analog Signal Range		0 to 1.5	V	
On Resistance, R _{ON}	4		Ω typ	V _D = 0 V to 1 V; I _S = −10 mA
	6	7	Ω max	
On Resistance Match Between Channels, ΔR _{ON}	0.15		Ω typ	V _D = 0 V to 1 V, I _S = −10 mA
		0.5	Ω max	
On Resistance Flatness, R _{FLAT(ON)}	1.5		Ω typ	V _D = 0 V to 1 V, I _S = −10 mA
		3	Ω max	
LEAKAGE CURRENTS				
Source Off Leakage, I _S (OFF)	±0.001		nA typ	V _D = 2 V/1 V, V _S = 1 V/2 V, see Figure 17
	±0.1	±0.25	nA max	
Drain Off Leakage, I _D (OFF)	±0.001		nA typ	V _D = 2 V/1 V, V _S = 1 V/2 V, see Figure 17
	±0.1	±0.25	nA max	
Channel On Leakage, I _D , I _S (ON)	±0.001		nA typ	V _D = V _S = 2 V/1 V, see Figure 18
	±0.1	±0.25	nA max	
DIGITAL INPUTS				
Input High Voltage, V _{INH}		2.0	V min	
Input Low Voltage, V _{INL}		0.4	V max	
Input Current				
I _{INL} or I _{INH}	0.001		μA typ	V _{IN} = V _{INL} or V _{INH}
		±0.1	μA max	
Digital Input Capacitance, C _{IN}		3	pF typ	
DYNAMIC CHARACTERISTICS ²				
t _{ON} , t _{ON} ($\overline{\text{EN}}$)		7	ns typ	C _L = 35 pF, R _L = 50 Ω, V _S = 1.5 V, see Figure 22
		14	ns max	
t _{OFF} , t _{OFF} ($\overline{\text{EN}}$)		4	ns typ	C _L = 35 pF, R _L = 50 Ω, V _S = 1.5 V, see Figure 22
		8	ns max	
Break-Before-Make Time Delay, t _D		3	ns typ	C _L = 35 pF, R _L = 50 Ω, V _{S1} = V _{S2} = 1.5 V, see Figure 23
		1	ns min	
Off Isolation		−65	dB typ	f = 10 MHz, R _L = 50 Ω
Channel-to-Channel Crosstalk		−70	dB typ	f = 10 MHz, R _L = 50 Ω, see Figure 21
Bandwidth −3 dB		400	MHz typ	R _L = 50 Ω, see Figure 19
Distortion		1.5	% typ	R _L = 100 Ω
Charge Injection		4	pC typ	C _L = 1 nF, see Figure 24, V _S = 0 V
C _S (OFF)		5	pF typ	
C _D (OFF)		7.5	pF typ	
C _D , C _S (ON)		12	pF typ	
POWER REQUIREMENTS				
I _{DD}		1	μA max	V _{DD} = 3.3 V
	0.001		μA typ	Digital inputs = 0 V or V _{DD}

¹ Temperature range for B version is -40°C to $+85^\circ\text{C}$.

² Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 3.

Parameters	Rating
V_{DD} to GND	–0.3 V to +6 V
Analog, Digital Inputs ¹	–0.3 V to $V_{DD} + 0.3$ V or 30 mA, whichever occurs first
Continuous Current, S or D	100 mA
Peak Current, S or D	300 mA (pulsed at 1 ms, 10% duty cycle max)
Operating Temperature Range	
Industrial (B Version)	–40°C to +85°C
Storage Temperature Range	–65°C to +150°C
Junction Temperature	150°C
Thermal Impedance, θ_{JA}	
16-Lead QSSOP	105.44°C/W ²
16-Lead LFCSP(3 mm × 3 mm)	48.7°C/W ²
Lead Temperature Soldering	
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C
Reflow Soldering (Pb-free)	
Peak Temperature	260°C (+0°C/–5°C)
Time at Peak Temperature	10 sec to 40 sec

¹ Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

² Measured with the device soldered on a four-layer board.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

ADG774A

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

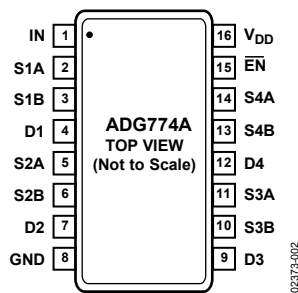
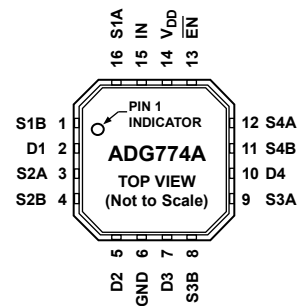


Figure 2. QSOP Pin Configuration



NOTES
1. THE EXPOSED PAD SHOULD BE TIED TO GND.

Figure 3. LFCSP Pin Configuration

Table 4. Pin Function Descriptions

Pin No.		Mnemonic	Function
QSOP	LFCSP		
1	15	IN	Logic Control Input.
2	16	S1A	Source Terminal 1A. May be an input or output.
3	1	S1B	Source Terminal 1B. May be an input or output.
4	2	D1	Drain Terminal D1. May be an input or output.
5	3	S2A	Source Terminal 2A. May be an input or output.
6	4	S2B	Source Terminal 2B. May be an input or output.
7	5	D2	Drain Terminal D2. May be an input or output.
8	6	GND	Ground (0 V) Reference.
9	7	D3	Drain Terminal D3. May be an input or output.
10	8	S3B	Source Terminal 3B. May be an input or output.
11	9	S3A	Source Terminal 3A. May be an input or output.
12	10	D4	Drain Terminal D4. May be an input or output.
13	11	S4B	Source Terminal 4B. May be an input or output.
14	12	S4A	Source Terminal 4A. May be an input or output.
15	13	EN	Logic Control Input. When high, all switches are disabled.
16	14	VDD	Most Positive Power Supply Potential.

Table 5. Truth Table

EN	IN	D1	D2	D3	D4	Function
1	X	Hi-Z	Hi-Z	Hi-Z	Hi-Z	DISABLE
0	0	S1A	S2A	S3A	S4A	IN = 0
0	1	S1B	S2B	S3B	S4B	IN = 1

TYPICAL PERFORMANCE CHARACTERISTICS

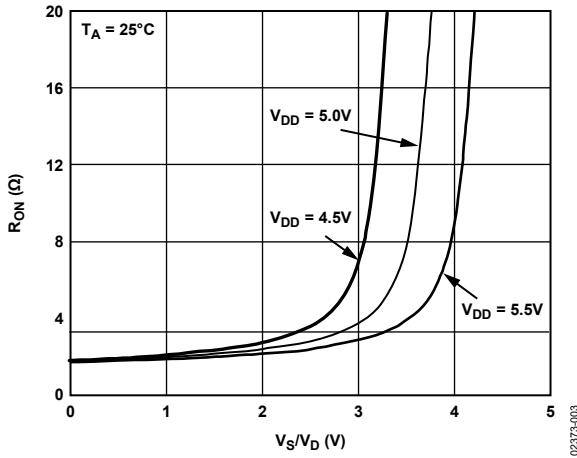


Figure 4. On Resistance as a Function of Drain (V_D) or Source (V_S) Voltage for $V_{DD} = 5\text{ V} \pm 10\%$

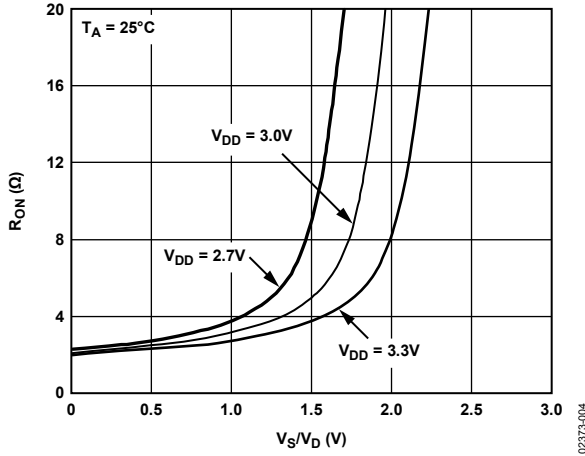


Figure 5. On Resistance as a Function of Drain (V_D) or Source (V_S) Voltage for $V_{DD} = 3\text{ V} \pm 10\%$

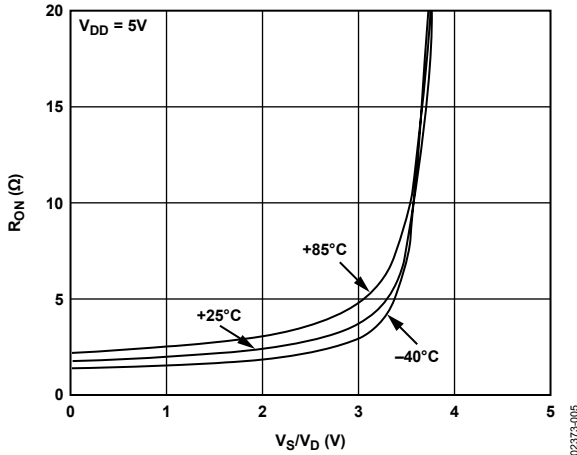


Figure 6. On Resistance as a Function of Drain (V_D) or Source (V_S) Voltage for Different Temperatures with 5 V Single Supplies

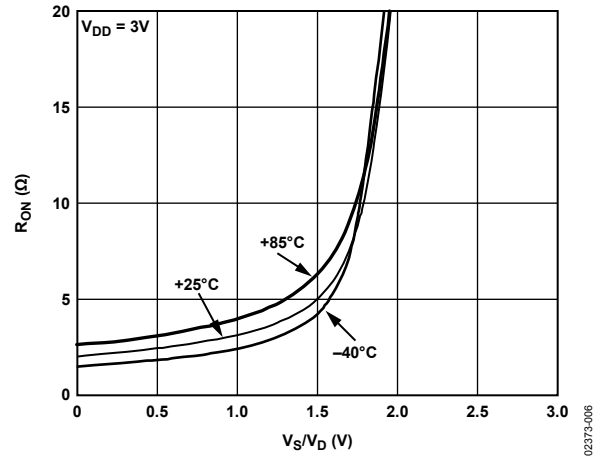


Figure 7. On Resistance as a Function of Drain (V_D) or Source (V_S) Voltage for Different Temperatures with 3 V Single Supplies

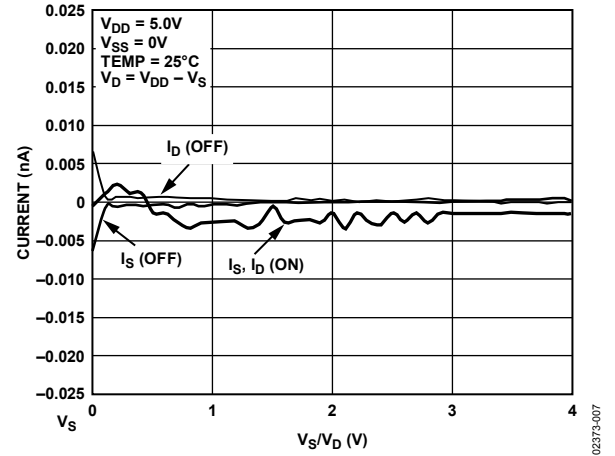


Figure 8. Leakage Current as a Function of Drain (V_D) or Source (V_S) Voltage for $V_{DD} = 5\text{ V}$

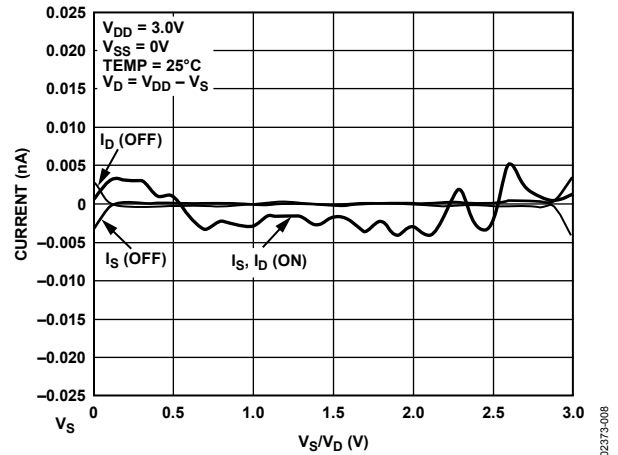


Figure 9. Leakage Current as a Function of Drain (V_D) or Source (V_S) Voltage for $V_{DD} = 3\text{ V}$

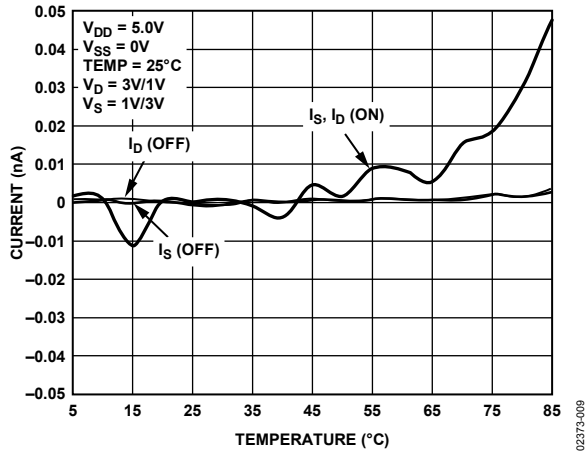


Figure 10. Leakage Current as a Function of Temperature, $V_{DD} = 5\text{ V}$

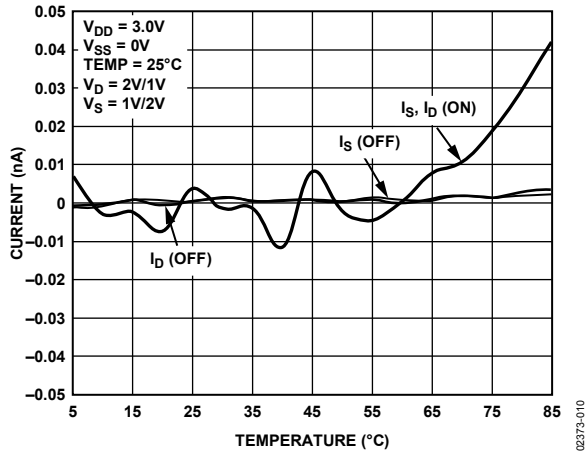


Figure 11. Leakage Current as a Function of Temperature, $V_{DD} = 3\text{ V}$

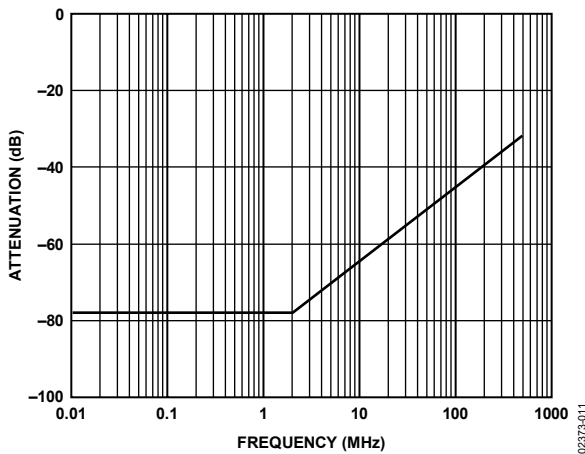


Figure 12. Off Isolation vs. Frequency

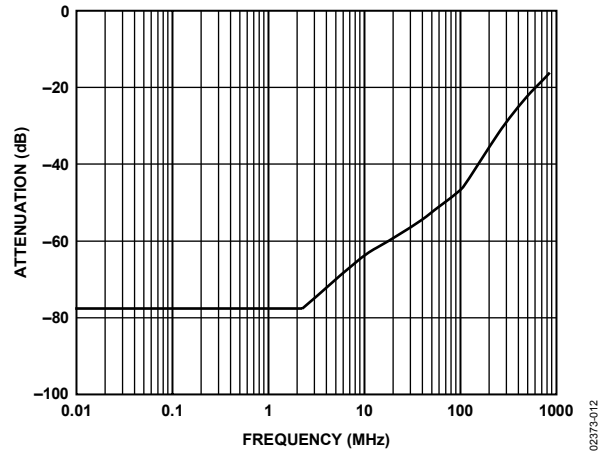


Figure 13. Crosstalk vs. Frequency

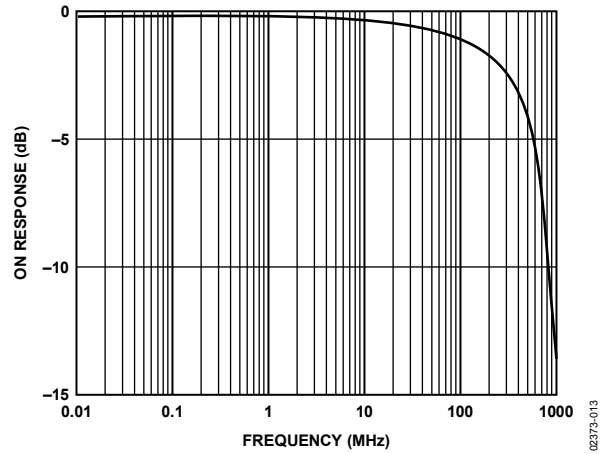


Figure 14. Bandwidth

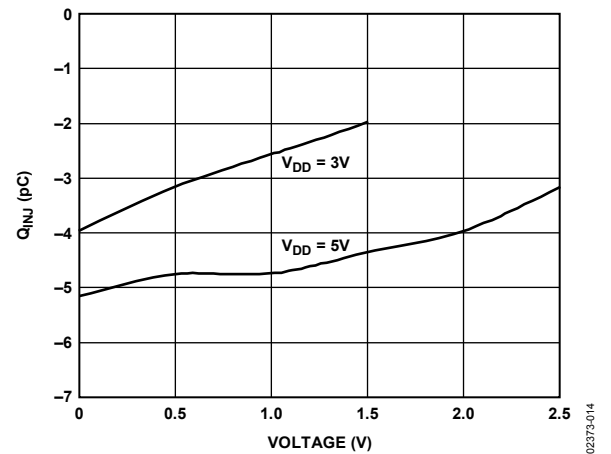


Figure 15. Charge Injection vs. Source Voltage

TEST CIRCUITS

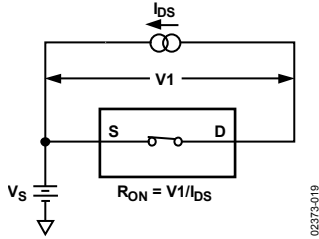


Figure 16. On Resistance

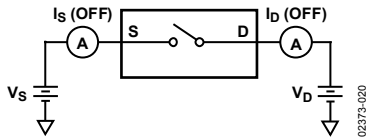


Figure 17. Off Leakage

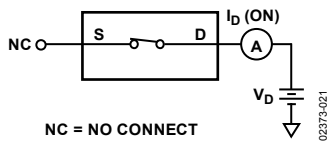


Figure 18. On Leakage

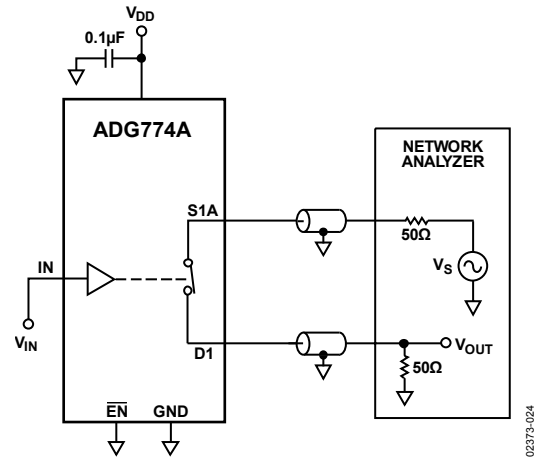


Figure 19. Bandwidth

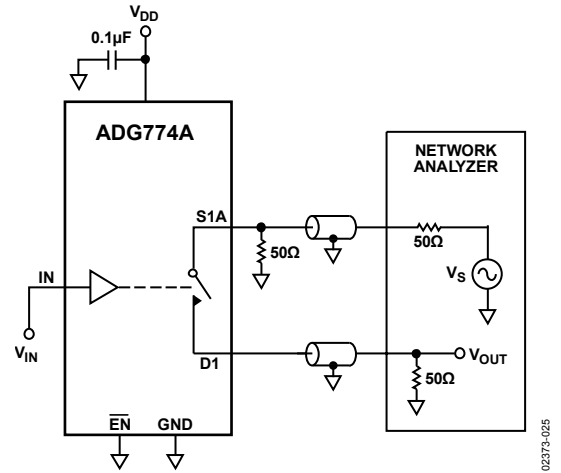


Figure 20. Off Isolation

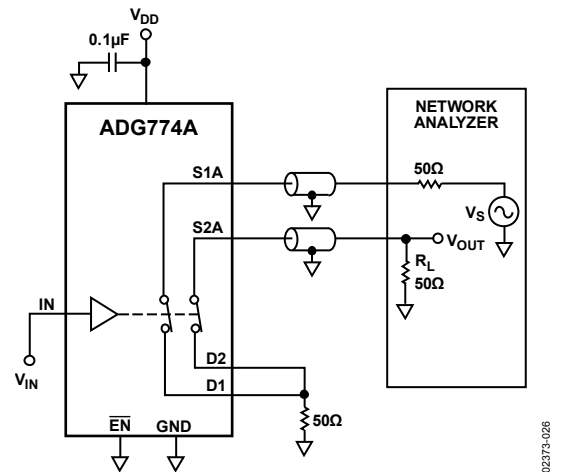


Figure 21. Channel-to-Channel Crosstalk

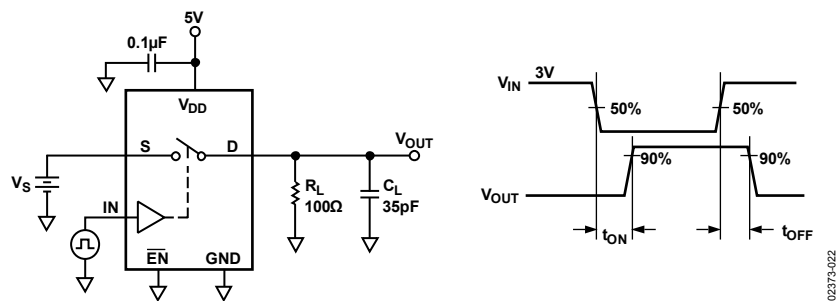


Figure 22. Switching Times

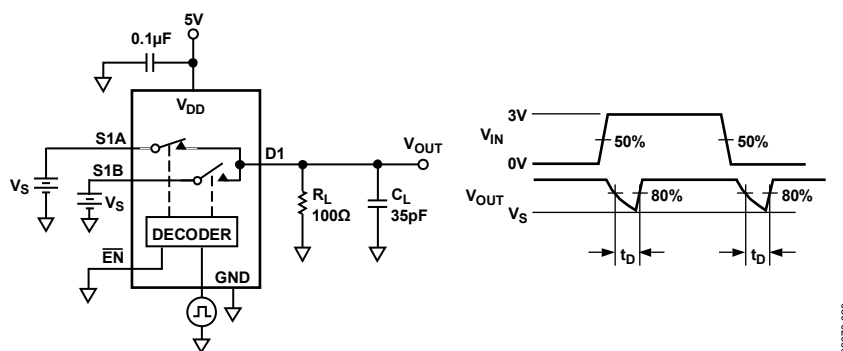


Figure 23. Break-Before-Make Time Delay

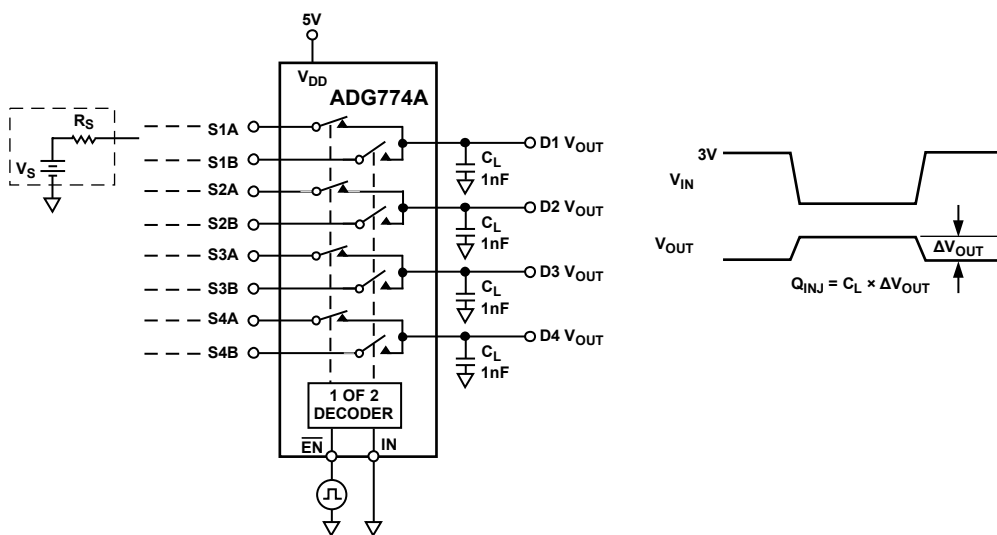


Figure 24. Charge Injection

TERMINOLOGY

V_{DD}

Most positive power supply potential.

GND

Ground (0 V) reference.

S

Source terminal. May be an input or output.

D

Drain terminal. May be an input or output.

IN

Logic control input.

$\overline{\text{EN}}$

Logic control input.

R_{ON}

Ohmic resistance between D and S.

ΔR_{ON}

On resistance match between any two channels, that is, $R_{ON \text{ max}} - R_{ON \text{ min}}$.

$R_{\text{FLAT(ON)}}$

Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.

I_S (OFF)

Source leakage current with the switch off.

I_D (OFF)

Drain leakage current with the switch off.

I_D, I_S (ON)

Channel leakage current with the switch on.

V_D (V_S)

Analog voltage on the D and S terminals.

C_S (OFF)

Off switch source capacitance.

C_D (OFF)

Off switch drain capacitance.

C_D, C_S (ON)

On switch capacitance.

t_{ON}

Delay between applying the digital control input and the output switching on. See Figure 22.

t_{OFF}

Delay between applying the digital control input and the output switching off.

t_D

Off time or on time measured between the 80% points of both switches when switching from one address state to another. See Figure 23.

Crosstalk

A measure of unwanted signal that is coupled through from one channel to another because of parasitic capacitance.

Off Isolation

A measure of unwanted signal coupling through an off switch.

Bandwidth

Frequency response of the switch in the on state measured at 3 dB down.

Distortion

$R_{\text{FLAT(ON)}}/R_L$

APPLICATION CIRCUITS

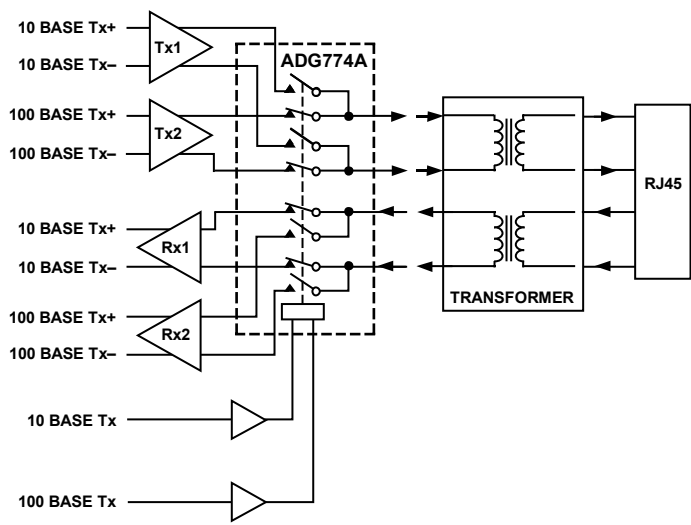


Figure 25. Full Duplex Transceiver

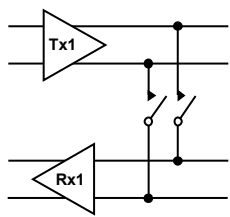


Figure 26. Loop Back

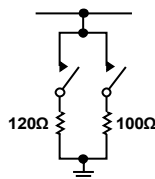


Figure 27. Line Termination

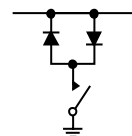
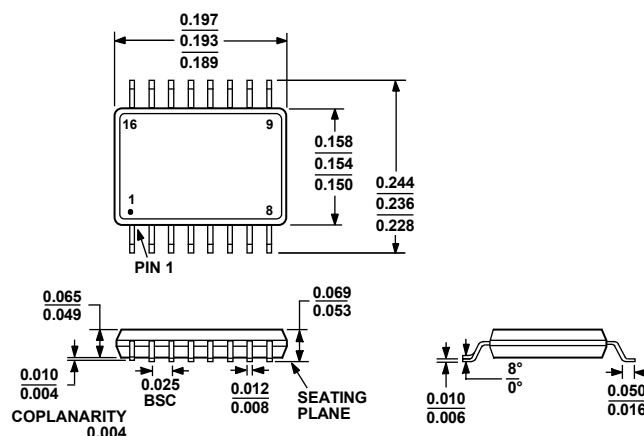


Figure 28. Line Clamp

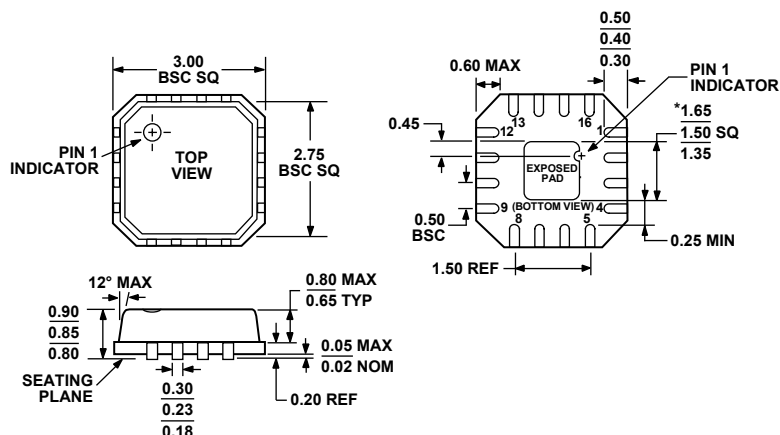
OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-137-AB

Figure 29. 16-Lead Shrink Small Outline Package [QSOP]
(RQ-16)

Dimensions shown in inches



*COMPLIANT TO JEDEC STANDARDS MO-220-VEED-2
EXCEPT FOR EXPOSED PAD DIMENSION.

Figure 30. 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ]
(CP-16-3)

Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
ADG774ABRQ	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG774ABRQ-REEL	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG774ABRQ-REEL7	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG774ABRQZ ¹	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG774ABRQZ-REEL ¹	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG774ABRQZ-REEL7 ¹	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG774ABCPZ-REEL	-40°C to +85°C	16-Lead Lead Frame Chip Scale Package [LFCSP_VQ]	CP-16-3

¹ Z = Pb-free part.

ADG774A

NOTES

NOTES

ADG774A

NOTES

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А